DCR6650H42

Phase Control Thyristor

Replaces DS6162-3 DS6162-4 September 2021 (LN41151)

FEATURES

- Double Side Cooling
- High Surge Capability

APPLICATIONS

- Crowbar
- High Power Drives
- High Voltage Power Supplies
- Static Switches

KEY PARAMETERS

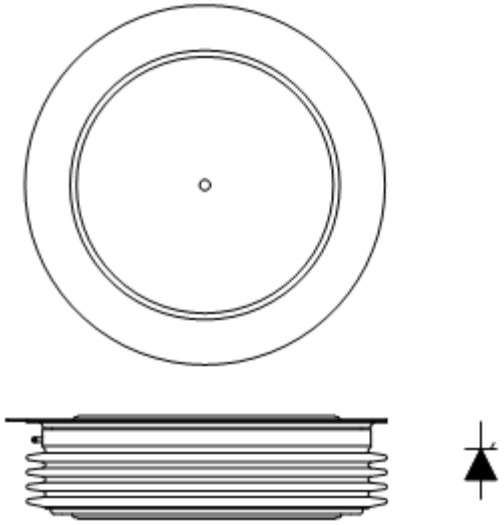
V_{DRM}	**4200V**
$I_{T(AV)}$	**6610A**
I_{TSM}	**98000A**
dV/dt*	**2000V/µs**
dI/dt	**500A/µs**

*** Higher dV/dt selections are available on request**

VOLTAGE RATINGS

Part and Ordering Number	Repetitive Peak Voltages V_{DRM} and V_{RRM} (V)	Conditions
DCR6650H42 DCR6650H40 DCR6650H38	4200 4000 3800	T_{vj} = -40°C to 125°C, I_{DRM} = I_{RRM} = 600mA, V_{DRM}, V_{RRM} t_p = 10ms V_{DSM} & V_{RSM} = V_{DRM} & V_{RRM} + 100V respectively

Lower voltage grades available.



Outline type code: H

(See Package Details for further information)

Fig. 1 Package outline

ORDERING INFORMATION

When ordering, select the required part number shown in the Voltage Ratings selection table.

For example:

DCR6650H42

Note: Please use the complete part number when ordering and quote this number in any future correspondence relating to your order.

CURRENT RATINGS

T_{case} = 60°C unless stated otherwise

Symbol	Parameter	Test Conditions	Max.	Units
Double Side Cooled				
$I_{T(AV)}$	Mean on-state current	Half wave resistive load	6610	A
$I_{T(RMS)}$	RMS value	-	10380	A
I_T	Continuous (direct) on-state current	-	9070	A

SURGE RATINGS

Symbol	Parameter	Test Conditions	Max.	Units
I_{TSM}	Surge (non-repetitive) on-state current	10ms half sine, T_{case} = 125°C	98.0	kA
I^2t	I^2t for fusing	V_R = 0	48.0	MA^2s

THERMAL AND MECHANICAL RATINGS

Symbol	Parameter	Test Conditions		Min.	Max.	Units
$R_{th(j-c)}$	Thermal resistance - junction to case	Double side cooled	DC	-	4.3	°C/kW
		Single side cooled	Anode DC	-	8.0	°C/kW
			Cathode DC	-	9.5	°C/kW
$R_{th(c-h)}$	Thermal resistance - case to heatsink	Clamping force 135kN (with mounting compound)	Double side	-	0.9	°C/kW
			Single side	-	1.8	°C/kW
T_{vj}	Virtual junction temperature	Blocking V_{DRM} / V_{RRM}		-	125	°C
T_{stg}	Storage temperature range			-55	125	°C
F_m	Clamping force			120	155	kN

DYNAMIC CHARACTERISTICS

Symbol	Parameter	Test Conditions		Min.	Max.	Units
I_{RRM}/I_{DRM}	Peak reverse and off-state current	At V_{RRM}/V_{DRM}, T_{case} = 125°C		-	600	mA
V_{TM}	Instantaneous forward voltage	At 4000A peak, T_j = 125°C		1.10	1.25	V
dV/dt	Max. linear rate of rise of off-state voltage	To 67% V_{DRM}, T_j = 125°C, gate open		-	2000	V/µs
dI/dt	Rate of rise of on-state current	From 67% V_{DRM} to 2x $I_{T(AV)}$ Gate source 30V, 10Ω t_r < 0.5µs, T_j = 125°C	Repetitive 50Hz	-	200	A/µs
			Non-repetitive	-	500	A/µs
$V_{T(TO)}$	Threshold voltage - Low level	1000A to 4500A at T_{case} = 125°C		-	0.79	V
	Threshold voltage - High level	4500A to 9000A at T_{case} = 125°C		-	0.97	V
r_T	On-state slope resistance - low level	1000A to 4500A at T_{case} = 125°C		-	0.12	mΩ
	On-state slope resistance - High level	4500A to 9000A at T_{case} = 125°C		-	0.08	mΩ
t_{gd}	Delay time	V_D = 67% V_{DRM}, gate source 30V, 10Ω t_r = 0.5µs, T_j = 25°C		-	3	µs
t_q	Turn-off time	I_T = 3000A, T_j = 125°C, V_R = 200V, dI/dt = 1A/µs, dV_{DR}/dt = 20V/µs linear		-	700	µs
Q_S	Stored charge	I_T = 3000A, T_j = 125°C, dI/dt = 1A/µs $V_{R(peak)}$ ~ 2500V, V_{RM} ~ 1700V		2800	6800	µC
I_{RR}	Reverse recovery current			41	70	A
I_L	Latching current	T_j = 25°C, V_D = 5V		-	3	A
I_H	Holding current	T_j = 25°C, R_{G-K} = ∞, I_{TM} = 500A, I_T = 5A		-	300	mA

GATE TRIGGER CHARACTERISTICS AND RATINGS

Symbol	Parameter	Test Conditions	Max.	Units
V_{GT}	Gate trigger voltage	V_{DRM} = 5V, T_{case} = 25°C	1.5	V
V_{GD}	Gate non-trigger voltage	At 50% V_{DRM}, T_{case} = 125°C	0.4	V
I_{GT}	Gate trigger current	V_{DRM} = 5V, T_{case} = 25°C	350	mA
I_{GD}	Gate non-trigger current	At 50% V_{DRM}, T_{case} = 125°C	10	mA

CURVES

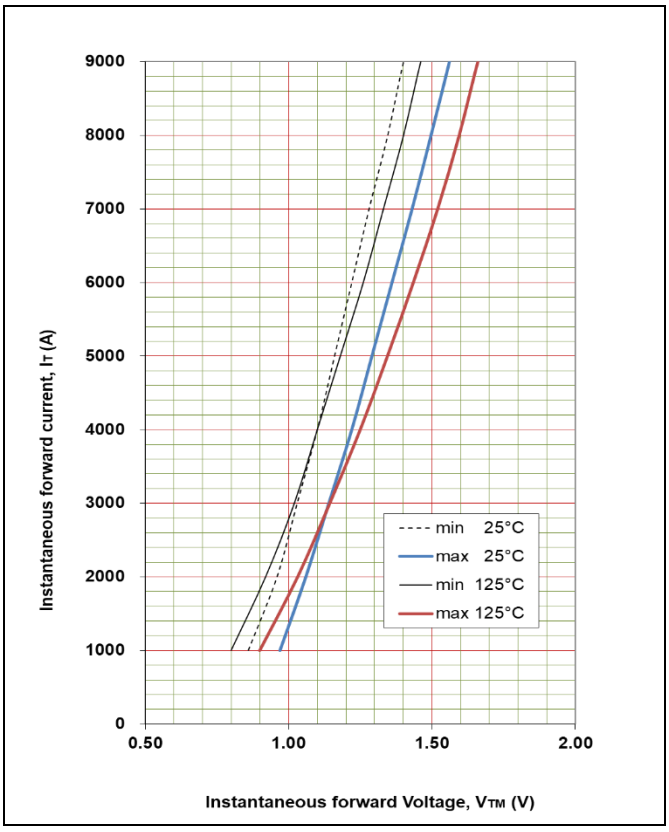


Fig. 2 Maximum & minimum on-state characteristics

V_{TM} EQUATION

$V_{TM} = A + B.\ln(I_T) + C.I_T + D.\sqrt{I_T}$

Where A = 1.075029
B = -0.093912
C = 0.000004
D = 0.014829

These values are valid for T_j = 125°C for I_T 1000A to 9000A

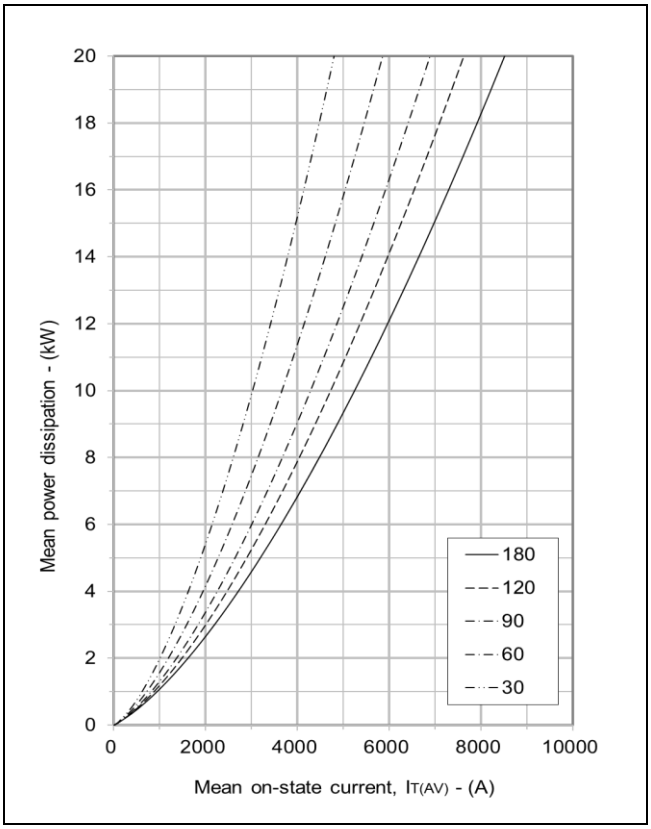


Fig. 3 On-state power dissipation - sine wave

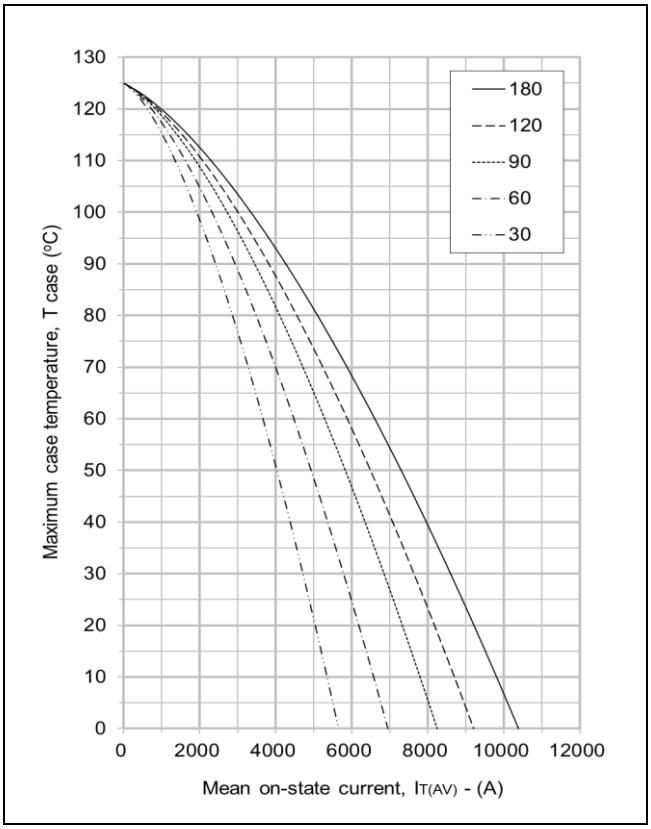


Fig. 4 Maximum permissible case temperature, double side cooled - sine wave

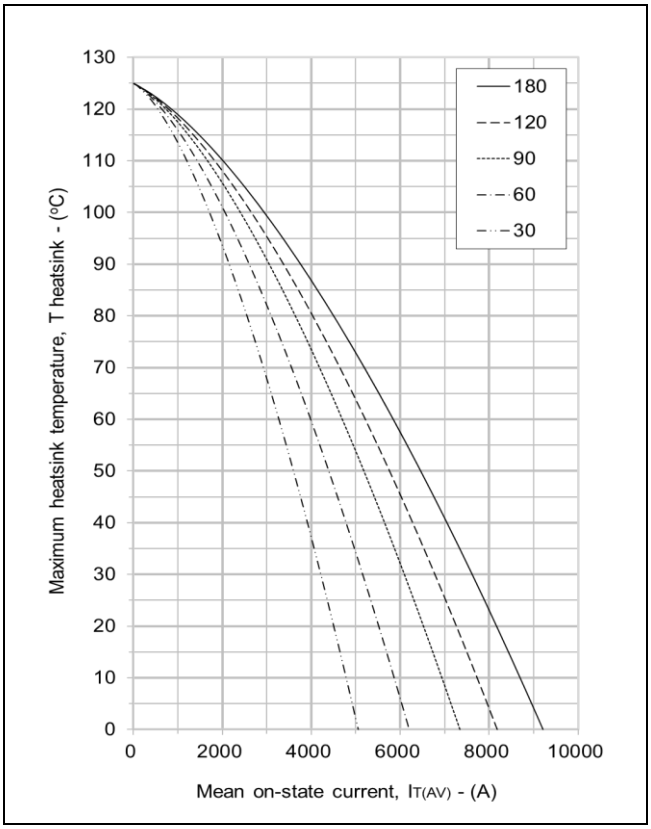


Fig. 5 Maximum permissible heatsink temperature, double side cooled - sine wave

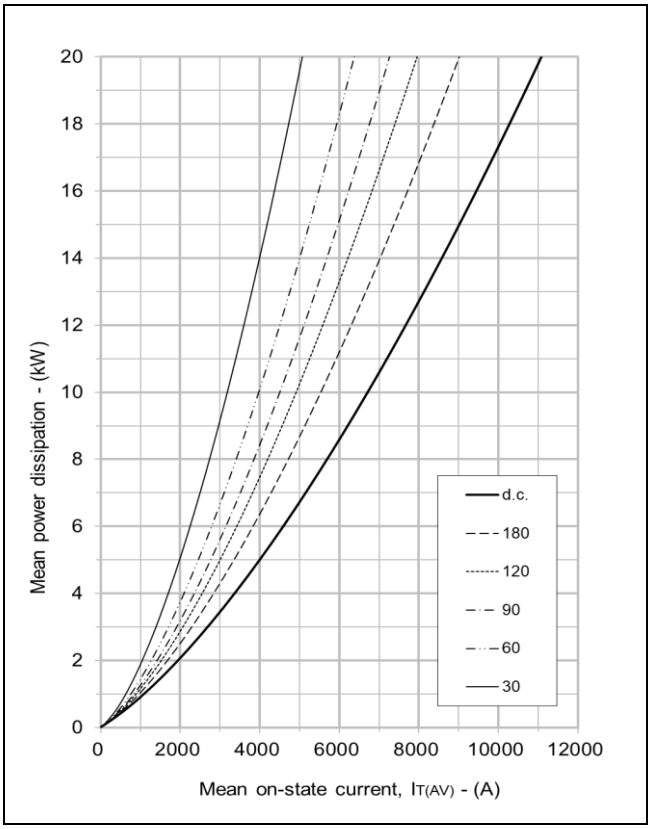


Fig. 6 On-state power dissipation - rectangular wave

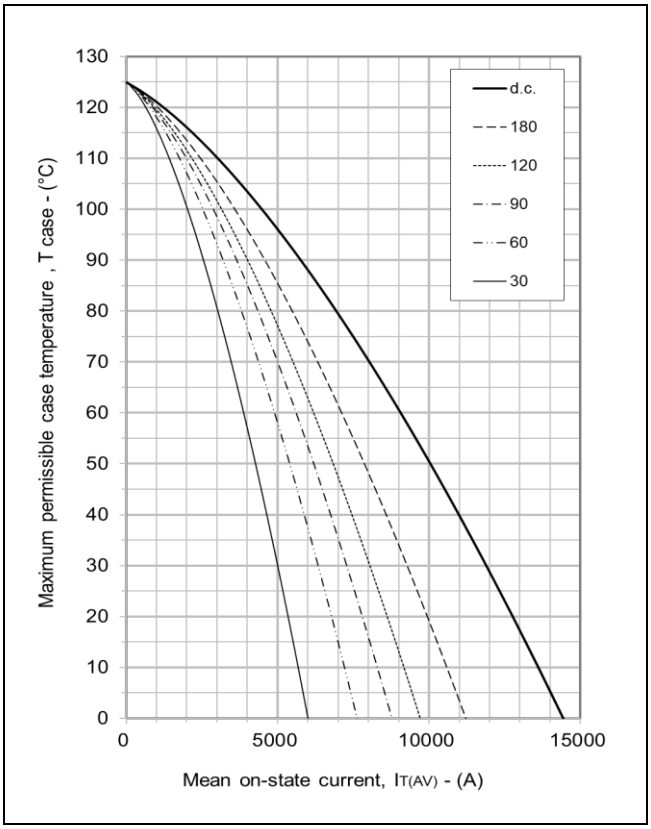


Fig. 7 Maximum permissible case temperature, double side cooled - rectangular wave

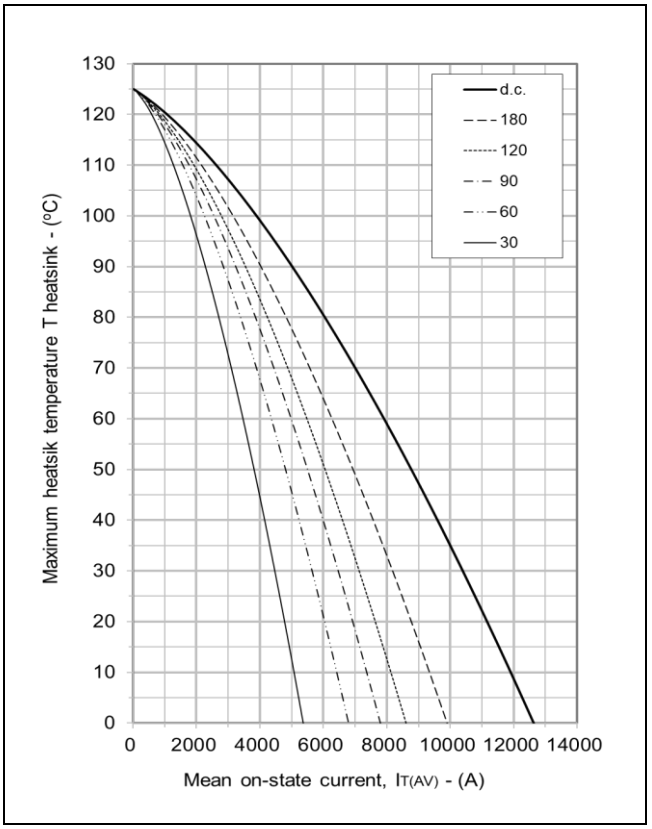
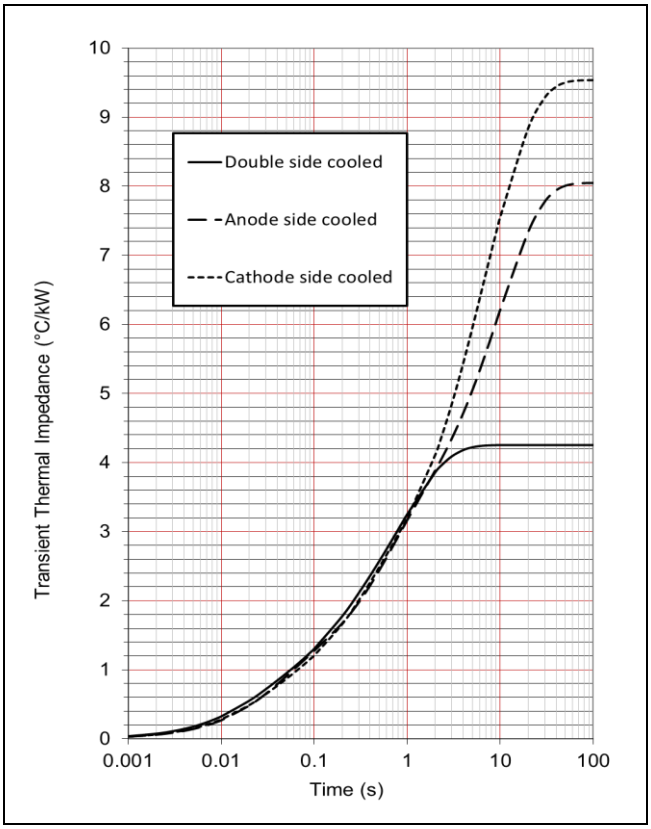


Fig. 8 Maximum permissible heatsink temperature, double side cooled - rectangular wave



		1	2	3	4
Double side cooled	Ri(°C/kW)	1.248	0.833	0.606	1.568
	Ti(s)	0.670	0.146	0.020	1.287
Anode side cooled	Ri(°C/kW)	0.512	1.946	0.920	4.666
	Ti(s)	2.898	0.505	0.036	10.647
Cathode side cooled	Ri(°C/kW)	2.417	1.537	0.626	4.959
	Ti(s)	3.441	0.269	0.024	10.172

$$Z_{th} = \sum_{i=1}^{i=4} R_i \cdot \left(1 - \exp\left(-\frac{T}{T_i}\right)\right)$$

$\Delta R_{th(j-c)}$ Conduction

Tables show the increments of thermal resistance $R_{th(j-c)}$ when the device operates at conduction angles other than d.c.

Double side cooling		
	ΔZ_{th} (z)	
θ°	sine.	rect.
180	0.38	0.26
120	0.44	0.37
90	0.49	0.43
60	0.54	0.49
30	0.58	0.55
15	0.60	0.58

Anode Side Cooling		
	ΔZ_{th} (z)	
θ°	sine.	rect.
180	0.32	0.23
120	0.36	0.31
90	0.41	0.36
60	0.45	0.40
30	0.48	0.45
15	0.49	0.48

Cathode Sided Cooling		
	ΔZ_{th} (z)	
θ°	sine.	rect.
180	0.33	0.23
120	0.38	0.33
90	0.43	0.37
60	0.47	0.43
30	0.51	0.48
15	0.52	0.51

Fig. 9 Maximum (limit) transient thermal impedance – junction to case (degC/kW)

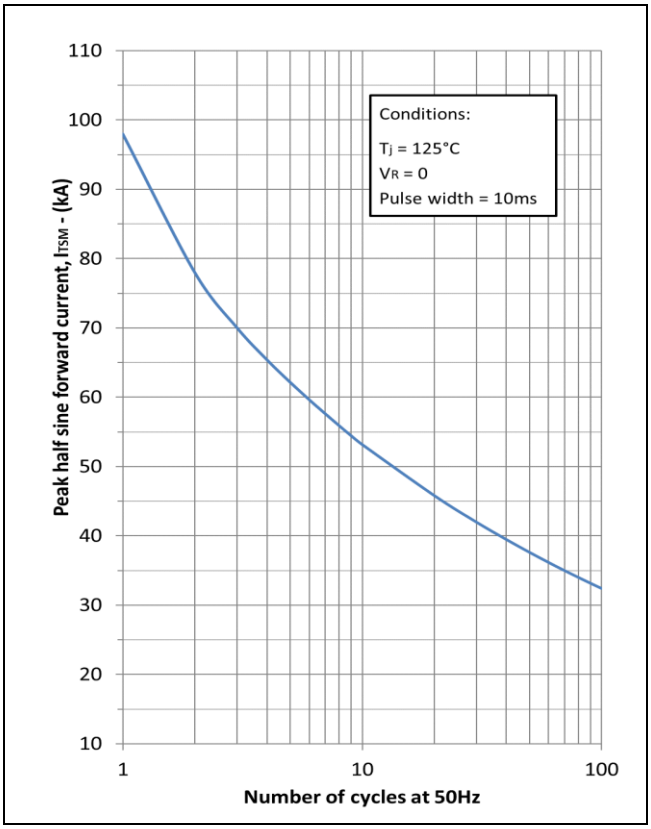


Fig. 10 Multi-cycle surge current

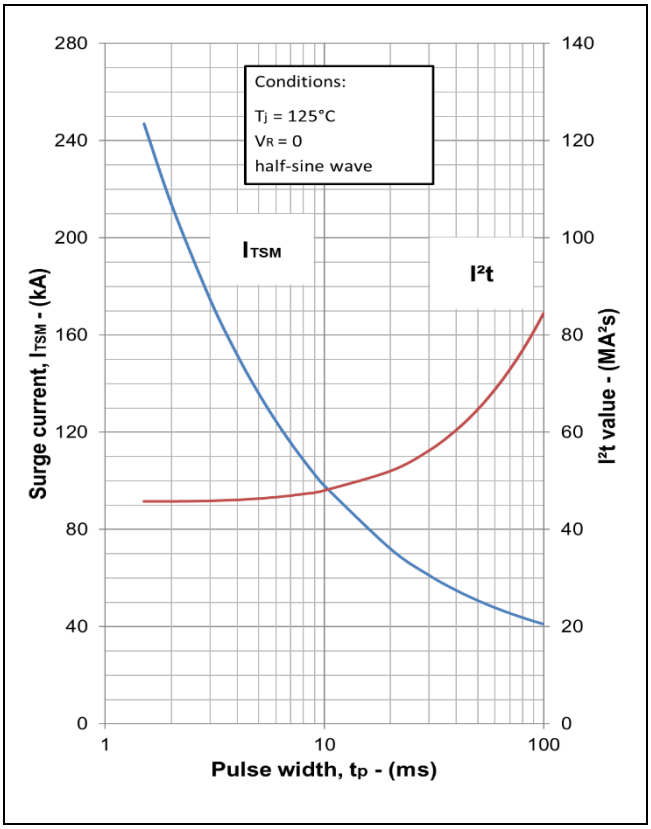


Fig. 11 Single-cycle surge current

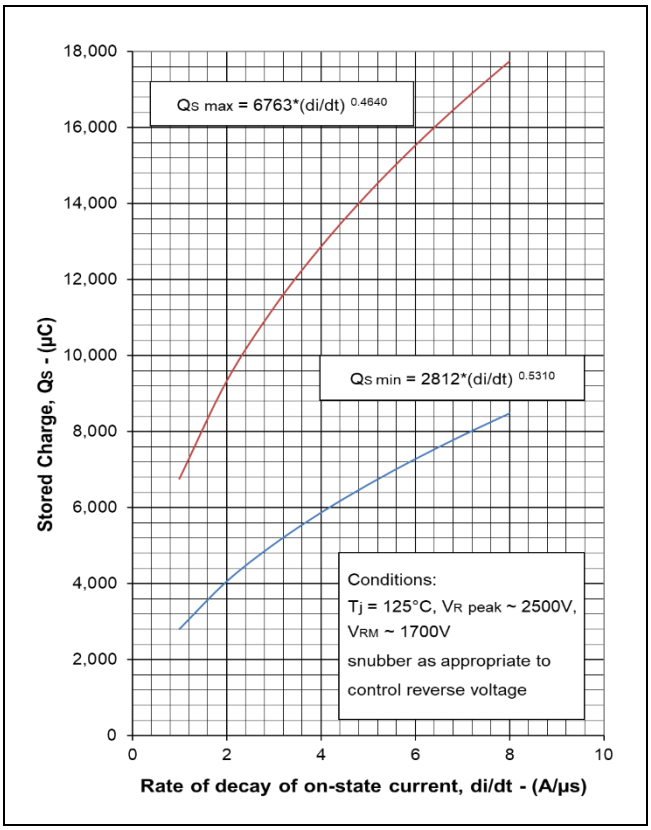


Fig. 12 Reverse recovery charge

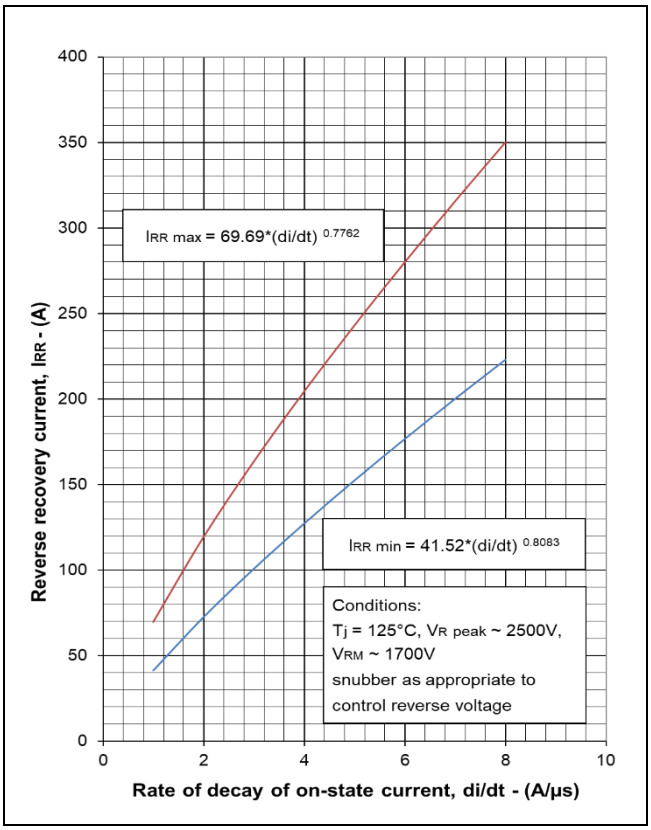


Fig. 13 Reverse recovery current

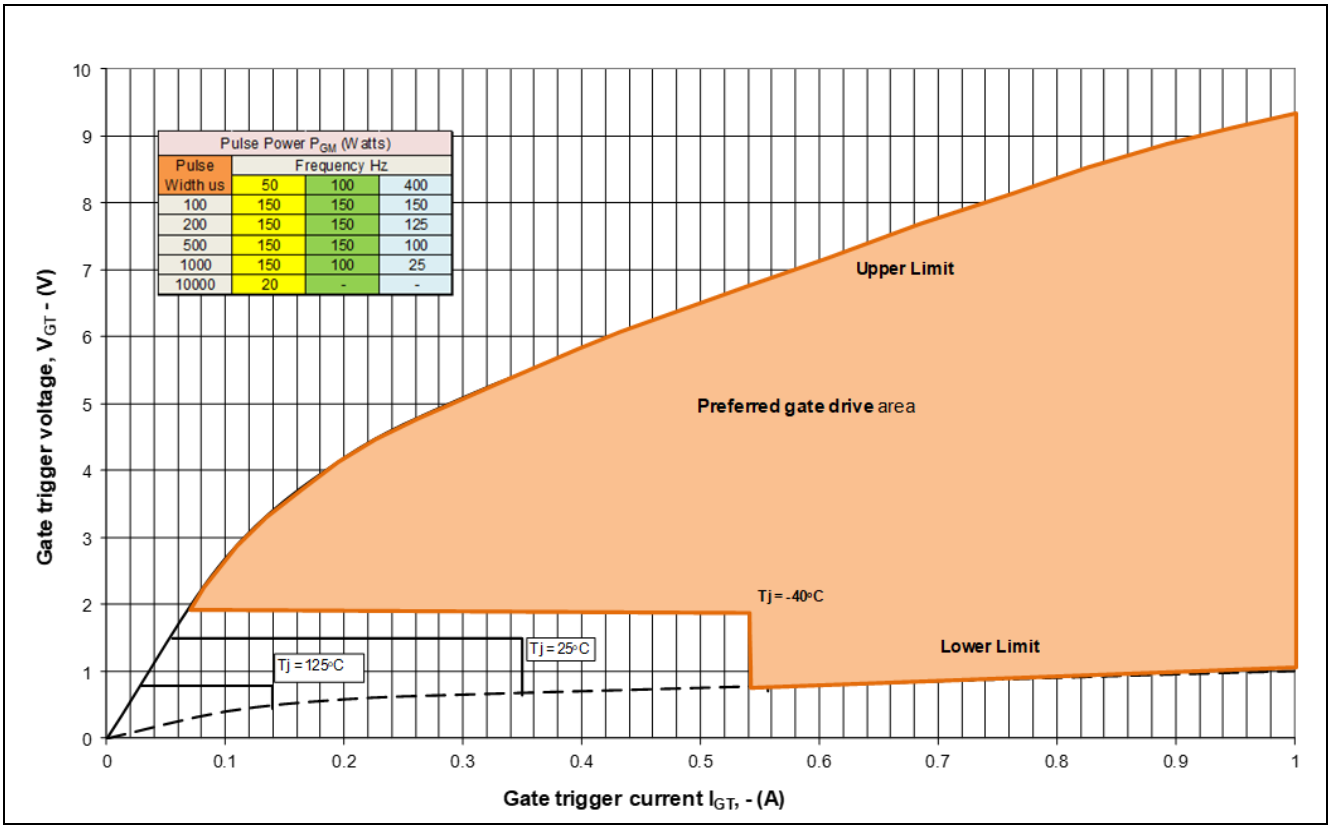


Fig. 14 Gate characteristics

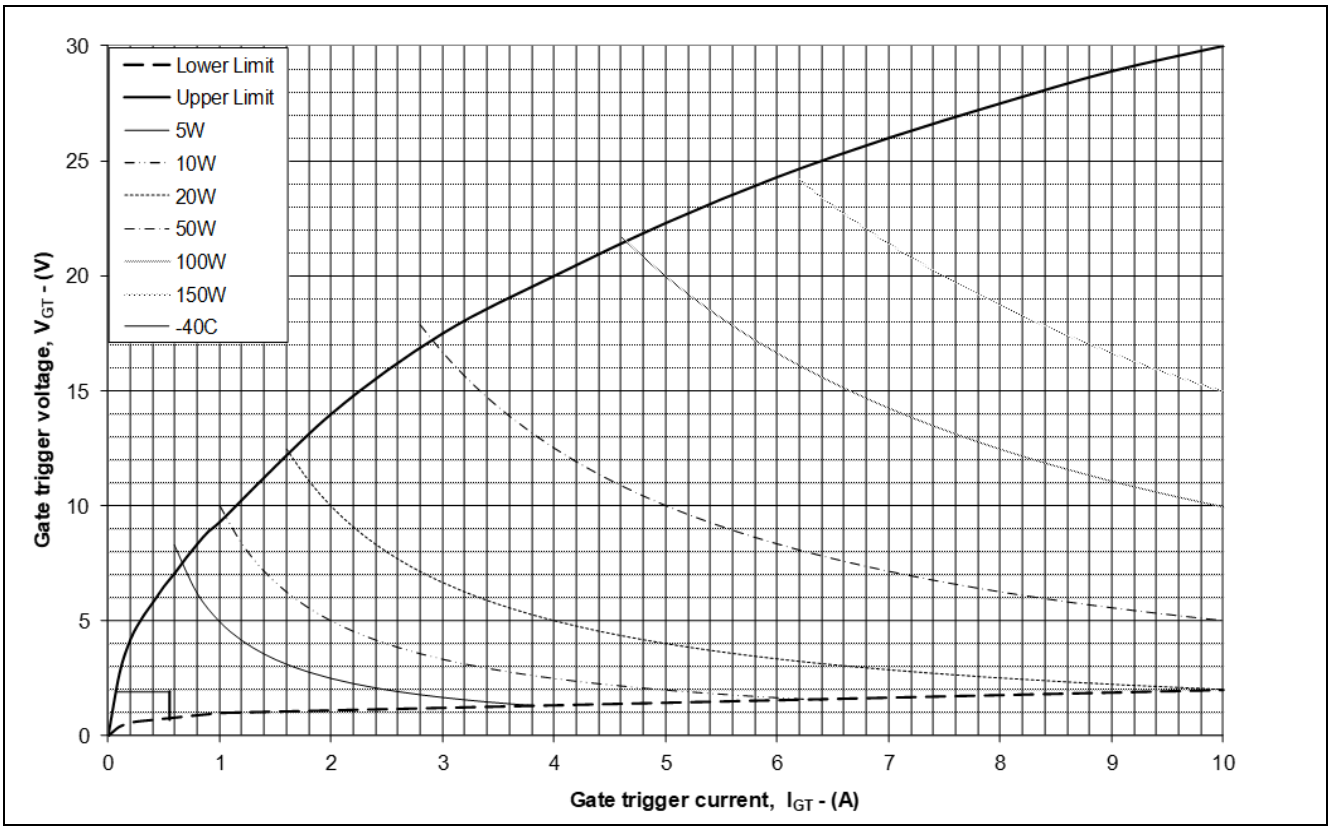


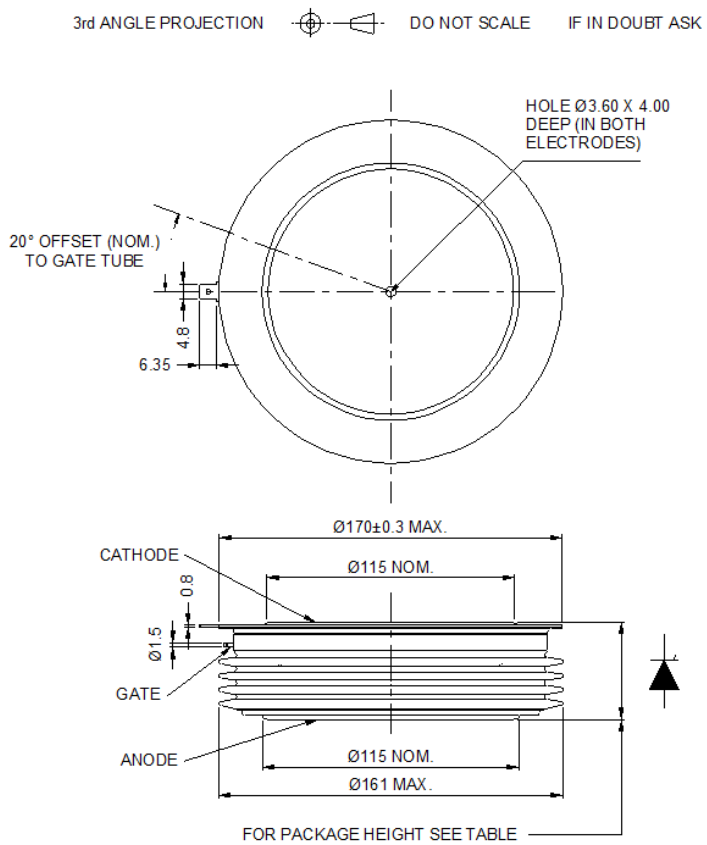
Fig. 15 Gate characteristics

PACKAGE DETAILS

For further package information, please contact Customer services.

All dimensions in mm, unless stated otherwise.

DO NOT SCALE



Device	Maximum Thickness (mm)	Minimum Thickness (mm)
DCR3980H85	35.7	35.1
DCR3640H85	35.7	35.1
DCR4660H65	35.4	34.7
DCR4420H65	35.4	34.7
DCR5890H52	35.1	34.5
DCR5240H52	35.1	34.5
DCR6650H42	**35.0**	**34.3**
DCR6140H42	35.0	34.3

Clamping force: 120kN to 155kN

Lead length: 420mm

Lead terminal connector: M4 ring

Package outline type code: H

Fig. 16 Package outline

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